



**DONGGUAN NANJING ELECTRONICS LTD.,**  
**SOT-23 Plastic-Encapsulate MOSFETS**

**NJ05N06** N Channel Advanced Power MOSFET

**Features**

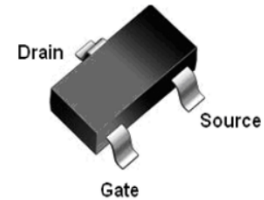
- Low  $R_{DS(on)}$  @  $V_{GS}=10V$
- 5V Logic Level Control
- HMB ESD Protection 2KV
- Pb-Free, RoHS Compliant

**Applications**

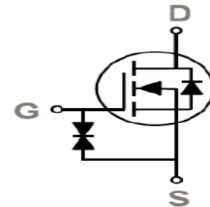
- LED Lighting Application,
- ON/OFF switch

**Order Information**

Product	Package	Marking	Packing
NJ05N06	SOT23	702	3000PCS/Reel



**SOT23**



**Maximum ratings ( $T_a=25^\circ\text{C}$  unless otherwise noted)**

Symbol	Parameter	Rating	Unit
<b>Common Ratings (<math>T_A=25^\circ\text{C}</math> Unless Otherwise Noted)</b>			
$V_{GS}$	Gate-Source Voltage	$\pm 20$	V
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	60	V
$T_J$	Maximum Junction Temperature	150	$^\circ\text{C}$
$T_{STG}$	Storage Temperature Range	-50 to 150	$^\circ\text{C}$
<b>Mounted on Large Heat Sink</b>			
$I_{DM}$	Pulse Drain Current Tested①	$T_A=25^\circ\text{C}$	1.8 A
$I_D$	Continuous Drain Current	$T_A=25^\circ\text{C}$	0.5 A
		$T_A=70^\circ\text{C}$	0.4 A
$P_D$	Maximum Power Dissipation	$T_A=25^\circ\text{C}$	0.3 W
		$T_A=70^\circ\text{C}$	0.2 W
$R_{\theta JA}$	Thermal Resistance Junction-Ambient	400	$^\circ\text{C/W}$

# MOSFET ELECTRICAL CHARACTERISTICS

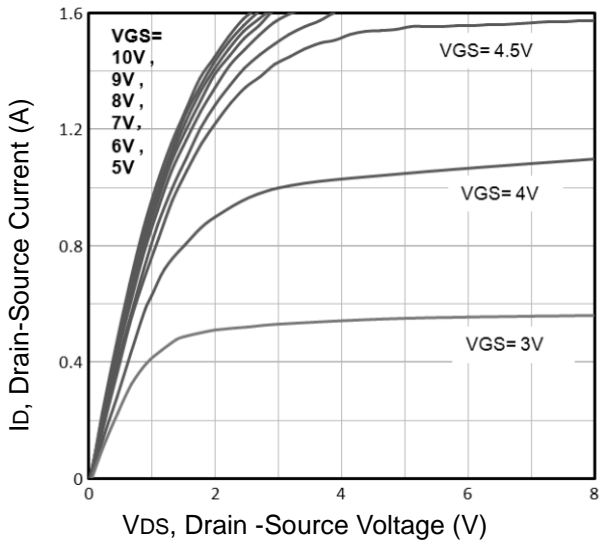
$T_a=25^\circ\text{C}$  unless otherwise specified

Symbol	Parameter	Condition	Min	Typ	Max	Unit
<b>Static Electrical Characteristics @ <math>T_J = 25^\circ\text{C}</math> (unless otherwise stated)</b>						
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	$V_{GS}=0V, I_D=250\mu A$	60	--	--	V
$I_{DSS}$	Zero Gate Voltage Drain Current( $T_A=25^\circ\text{C}$ )	$V_{DS}=60V, V_{GS}=0V$	--	--	1	$\mu A$
	Zero Gate Voltage Drain Current( $T_A=125^\circ\text{C}$ )	$V_{DS}=50V, V_{GS}=0V$	--	--	100	$\mu A$
$I_{GSS}$	Gate-Body Leakage Current	$V_{GS}=\pm 20V, V_{DS}=0V$	--	--	$\pm 10$	$\mu A$
$V_{GS(TH)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}, I_D=250\mu A$	1.0	1.6	2.5	V
$R_{DS(ON)}$	Drain-Source On-State Resistance②	$V_{GS}=10V, I_D=0.5A$	--	1.9	3	$\Omega$
$R_{DS(ON)}$	Drain-Source On-State Resistance②	$V_{GS}=4.5V, I_D=0.3A$	--	2.4	4	$\Omega$
<b>Dynamic Electrical Characteristics @ <math>T_J = 25^\circ\text{C}</math> (unless otherwise stated)</b>						
$C_{iss}$	Input Capacitance	$V_{DS}=30V, V_{GS}=0V,$ $f=1\text{MHz}$	--	23.8	--	pF
$C_{oss}$	Output Capacitance		--	3.9	--	pF
$C_{rss}$	Reverse Transfer Capacitance		--	1.5	--	pF
$Q_g$	Total Gate Charge	$V_{DS}=30V$ $I_D=0.5A,$ $V_{GS}=10V$	--	0.93	--	nC
$Q_{gs}$	Gate Source Charge		--	0.18	--	nC
$Q_{gd}$	Gate Drain Charge		--	0.31	--	nC
<b>Switching Characteristics</b>						
$t_{d(on)}$	Turn on Delay Time	$V_{DD}=30V,$ $I_D=0.3A,$ $R_G=3.3\Omega,$ $V_{GS}=10V$	--	6	--	ns
$t_r$	Turn on Rise Time		--	3.5	--	ns
$t_{d(off)}$	Turn Off Delay Time		-	20	--	ns
$t_f$	Turn Off Fall Time		--	5.9	--	ns
<b>Source Drain Diode Characteristics</b>						
$I_{SD}$	Source drain current(Body Diode)	$T_A=25^\circ\text{C}$	--	--	0.2	A
$V_{SD}$	Forward on voltage②	$T_J=25^\circ\text{C}, I_{SD}=0.5A,$ $V_{GS}=0V$	--	0.78	1.2	V

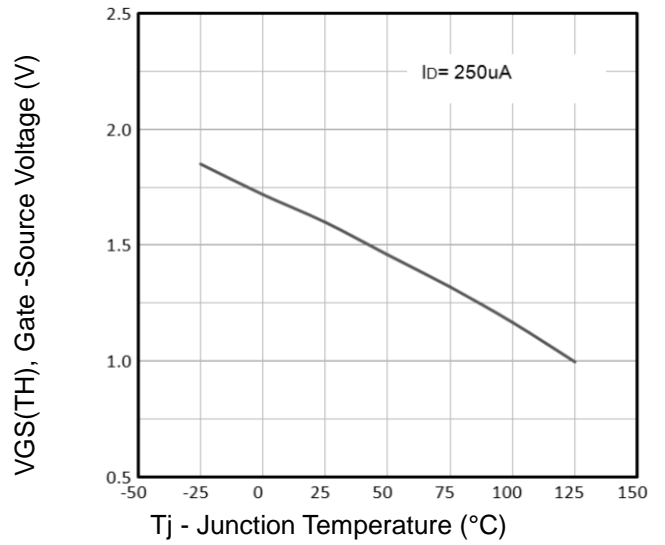
Notes:

- ① Pulse width limited by maximum allowable junction temperature
- ② Pulse test ; Pulse width $\leq 300\mu s$ , duty cycle $\leq 2\%$ .

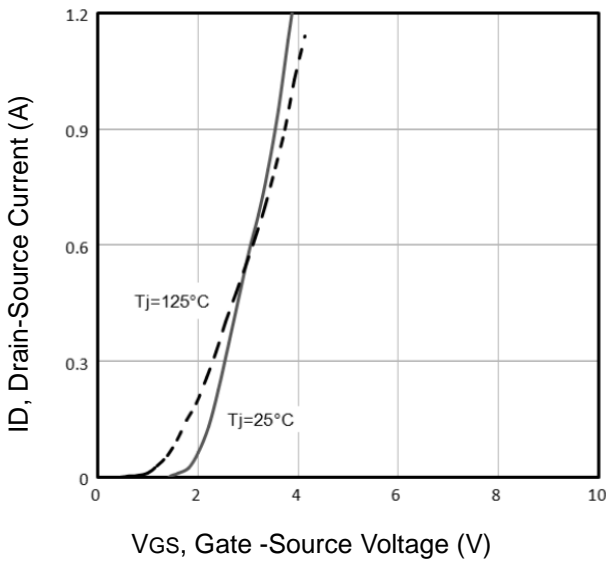
# Typical Characteristics



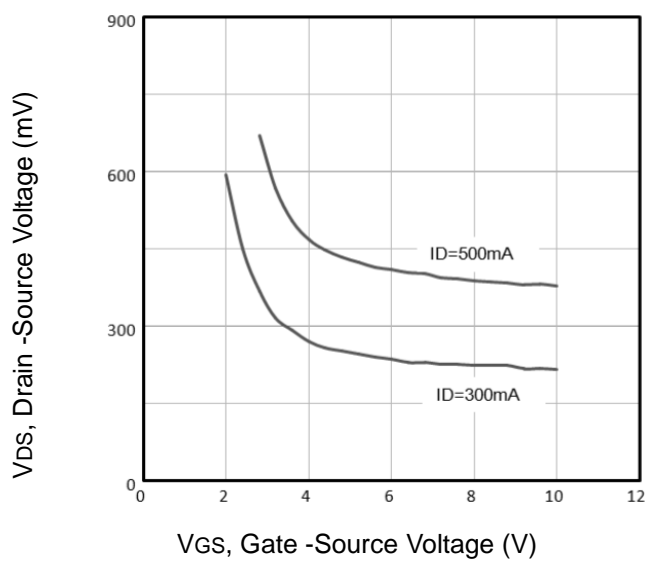
**Fig1.** Typical Output Characteristics



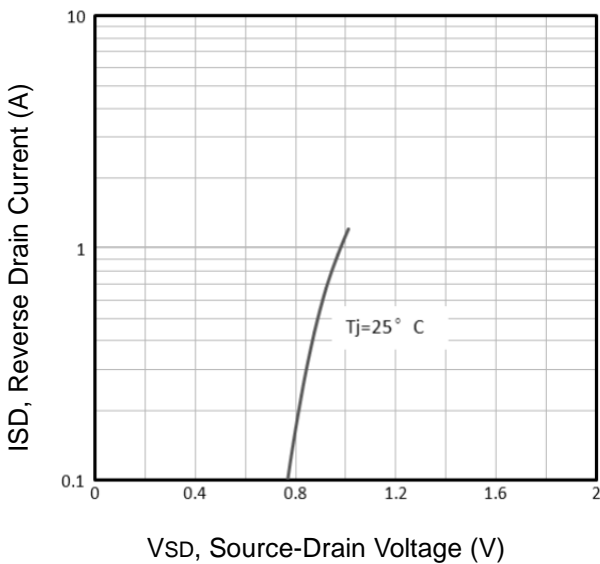
**Fig2.** Normalized Threshold Voltage Vs. Temperature



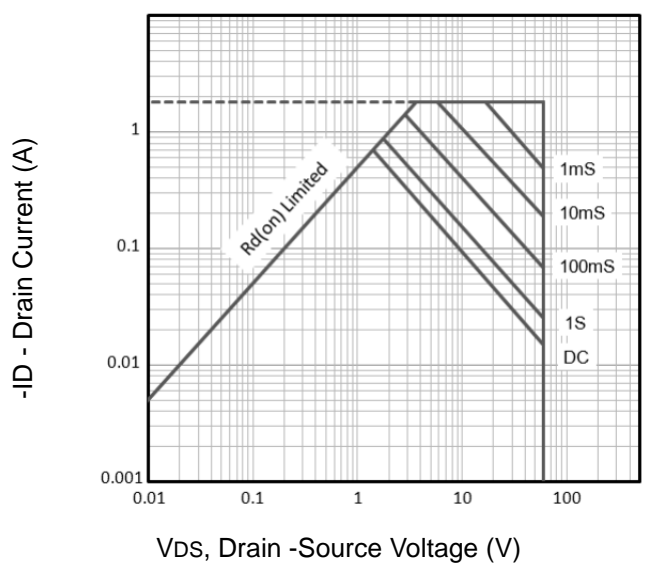
**Fig3.** Typical Transfer Characteristics



**Fig4.** Drain-Source Voltage vs Gate-Source Voltage

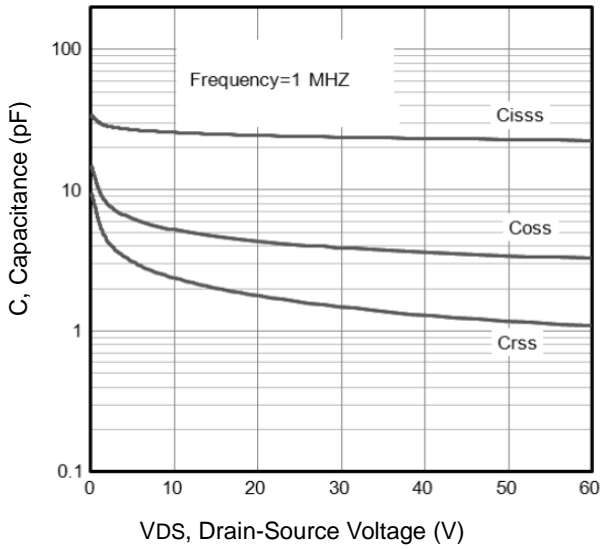


**Fig5.** Typical Source-Drain Diode Forward Voltage

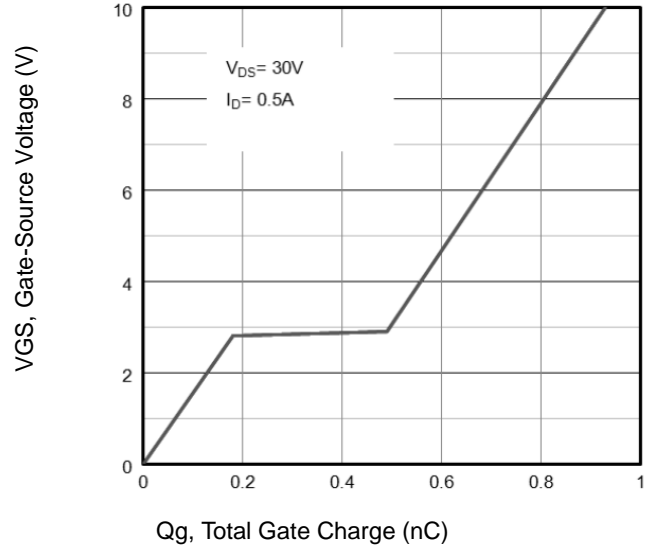


**Fig6.** Maximum Safe Operating Area

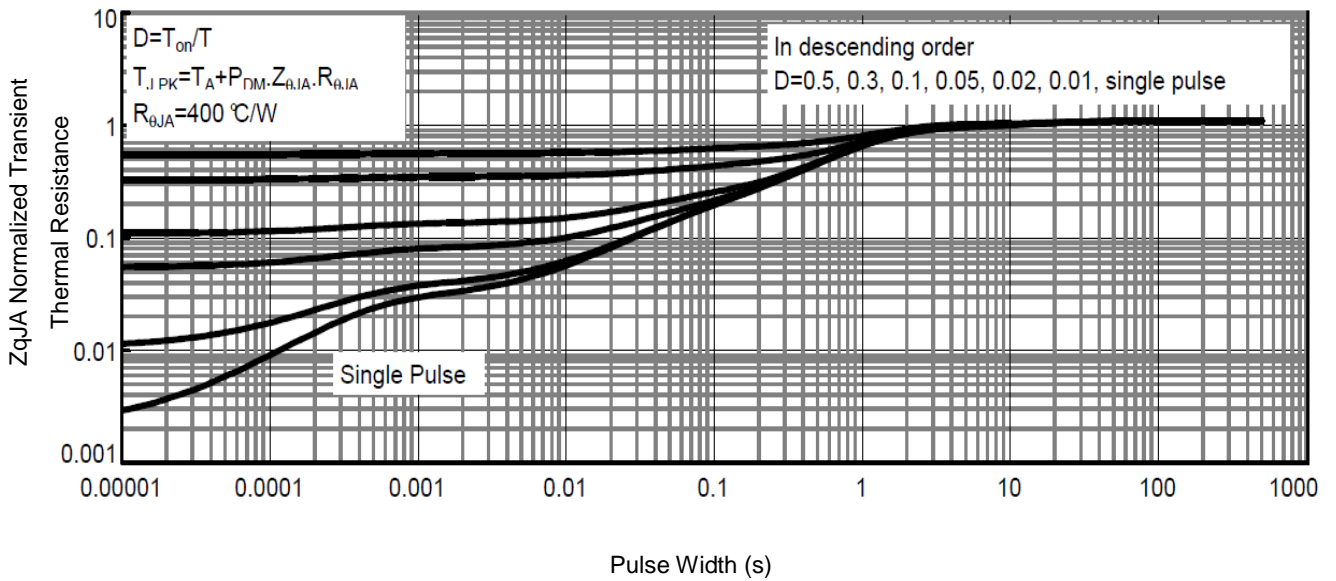
# Typical Characteristics



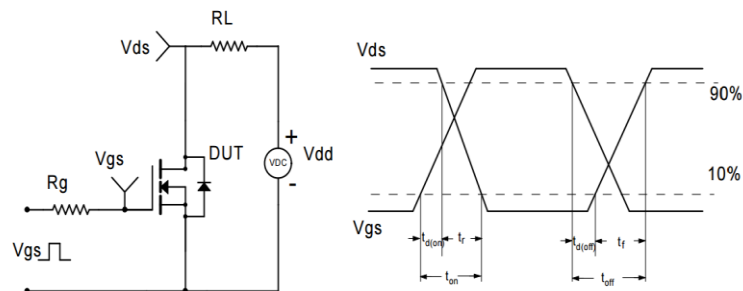
**Fig7.** Typical Capacitance Vs. Drain-Source Voltage



**Fig8.** Typical Gate Charge Vs. Gate-Source Voltage

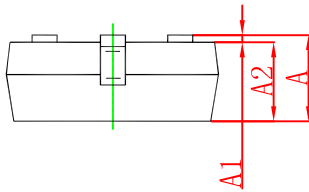
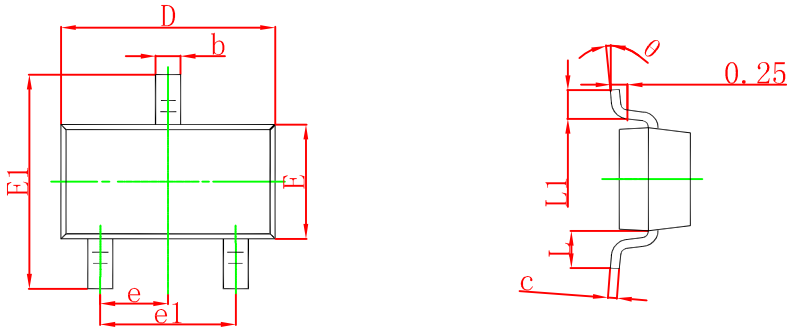


**Fig9.** Normalized Maximum Transient Thermal Impedance



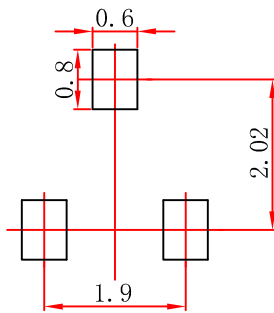
**Fig10.** Switching Time Test Circuit and waveforms

## SOT-23 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

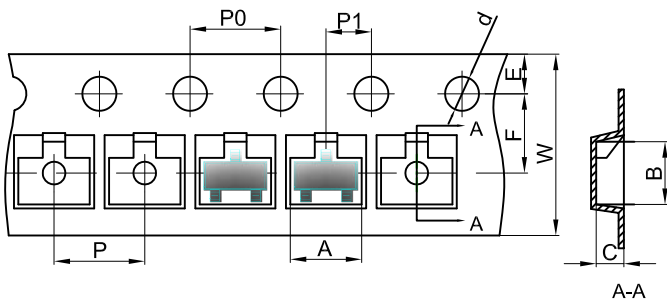
## SOT-23 Suggested Pad Layout



- Note:
1. Controlling dimension: in millimeters.
  2. General tolerance:  $\pm 0.05$  mm.
  3. The pad layout is for reference purposes only.

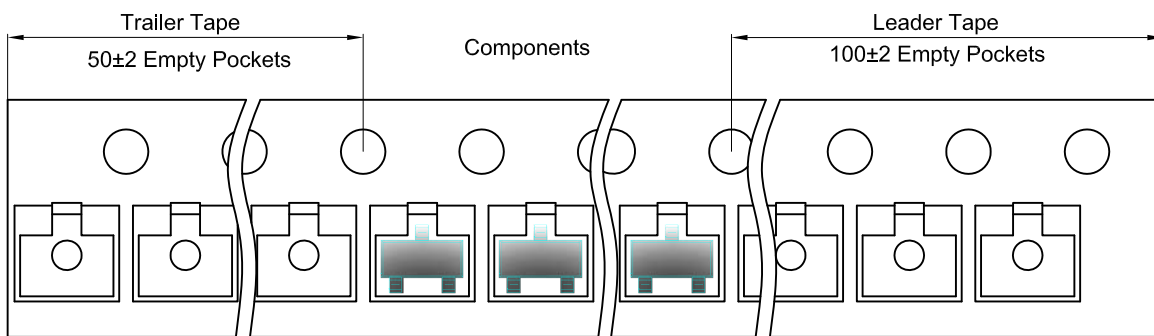
# SOT-23 Tape and Reel

## SOT-23 Embossed Carrier Tape

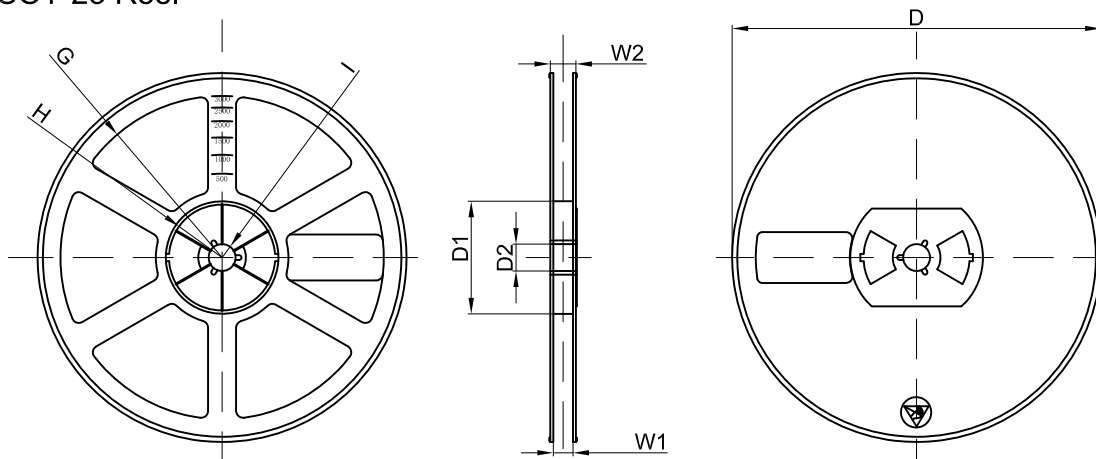


Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-23	3.15	2.77	1.22	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

## SOT-23 Tape Leader and Trailer



## SOT-23 Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
7" Dia	Ø178.00	54.40	13.00	R78.00	R25.60	R6.50	9.50	12.30

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	45,000 pcs	203×203×195	180,000 pcs	438×438×220	